

RJH60F0DPK

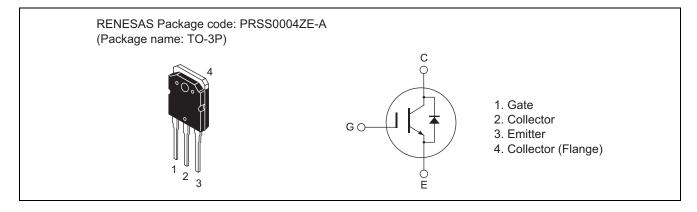
Silicon N Channel IGBT High Speed Power Switching

REJ03G1834-0100 Rev.1.00 Oct 13, 2009

Features

- High speed switching
- Low on-state voltage
- Fast recovery diode

Outline



Absolute Maximum Ratings

 $(Tc = 25^{\circ}C)$

Item		Symbol	Ratings	Unit
Collector to emitter voltage		V _{CES}	600	V
Gate to emitter voltage		V _{GES}	±30	V
Collector current	Tc = 25 °C	I _C Note1	50	Α
	Tc = 100°C	I _C Note1	25	Α
Collector peak current		ic(peak) Note1	100	Α
Collector to emitter diode forward peak current		i _{DF} (peak) Note2	100	Α
Collector dissipation		P _C Note3	201.6	W
Channel temperature		Tj	150	°C
Storage temperature		Tstg	-55 to +150	°C

Notes: 1. Pulse width limited by safe operating area.

- 2. $PW \le 5 \mu s$, duty cycle $\le 1\%$
- 3. Value at Tc = 25°C

RJH60F0DPK Preliminary

Electrical Characteristics

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 $(Tj = 25^{\circ}C)$

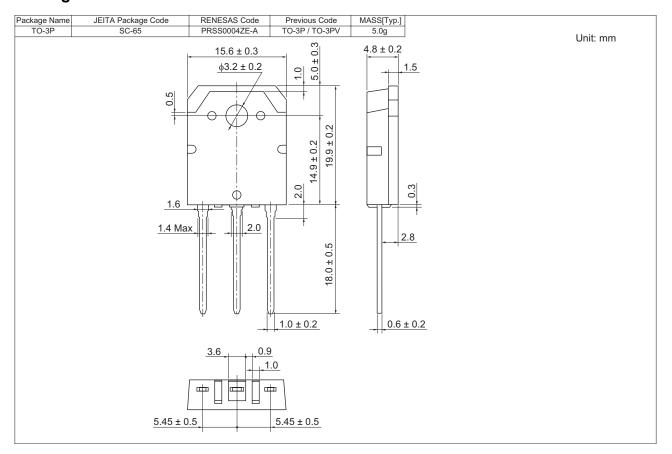
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Zero gate voltage collector current	I _{CES}	_	_	100	μА	$V_{CE} = 600V, V_{GE} = 0$
Gate to emitter leak current	I _{GES}	_	_	±1	μА	$V_{GE} = \pm 30 \text{ V}, V_{CE} = 0$
Gate to emitter cutoff voltage	$V_{\text{GE(off)}}$	4	_	8	V	V _{CE} = 10V, I _C = 1 mA
Collector to emitter saturation voltage	V _{CE(sat)}		1.4	1.82	V	$I_C = 25 \text{ A}, V_{GE} = 15V^{\text{Note4}}$
			1.7	_	V	$I_{\rm C}$ = 50 A, $V_{\rm GE}$ = 15V $^{\rm Note4}$
Switching time	t _f	_	90	_	ns	I _C = 30 A, Resistive Load
						V _{CC} = 300 V
						V _{GE} = 15 V
						$Rg = 5 \Omega$ Note4
C-E diode forward voltage	V _{ECF1}	_	1.6	2.1	V	I _F = 20 A Note4
C-E diode forward voltage	V _{ECF2}	_	1.8	_	V	I _F = 40 A Note4
C-E diode reverse recovery time	t _{rr}	_	140	_	ns	I _F = 20 A
						di _F /dt = 100 A/μs

Notes: 4. Pulse test

RJH60F0DPK **Preliminary**

Package Dimensions

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Ordering Information

Part No.	Quantity	Shipping Container
RJH60F0DPK-00-T0	360 pcs	Box (Tube)

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- Notes:

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